

## **MBR1060CD** Surface Mount Schottky Barrier Rectifier **TO-252AA** Voltage 60 V Current 10 A Features • Low power loss, high efficiency • High surge current capability • Lead free in compliance with EU RoHS 2.0 • Green molding compound as per IEC 61249 standard **Mechanical Data** • Case : TO-252AA Package • Terminals : Solderable per MIL-STD-750, Method 2026 2)(4 • Approx. Weight : 0.3217 grams

#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub> = 25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Maximum Repetitive Peak Reverse Voltage		Vrrm	60	V
Maximum RMS Voltage		V <sub>RMS</sub>	42	V
Maximum DC Blocking Voltage		V <sub>DC</sub>	60	V
Maximum Average Forward Current	IF(AV)	10	A	
Peak Forward Surge Current : 8.3 ms Single Half Sine- Wave Superimposed On Rated Load		IFSM	120	А
Typical Junction Capacitance Measured at 1 MHZ And Applied $V_R = 4 V$		CJ	180	pF
	(Note 1)	Reja	50	
Typical Thermal Resistance per diode	(Note 2)	Rejc	5.8	°C/W
	(Note 2)	Rejl	3.3	
Operating Junction Temperature Range		TJ	-55~175	°C
Storage Temperature Range		T <sub>STG</sub>	-55~175	°C



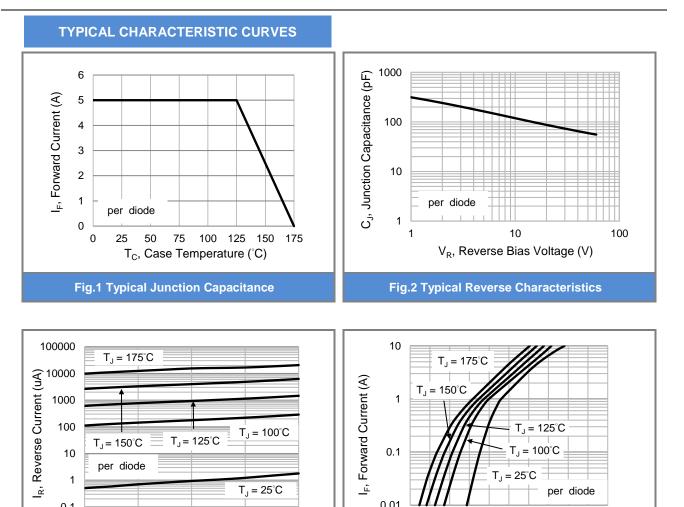
#### **Electrical Characteristics** (T<sub>A</sub> = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Forward Voltage Per Diode	VF	I <sub>F</sub> = 1 A, T <sub>J</sub> = 25 °C	-	0.46	-	V
		I⊧ = 3 A, TJ = 25 °C	-	0.59	-	
		I <sub>F</sub> = 5 A, T <sub>J</sub> = 25 °C	-	0.66	0.74	
		I <sub>F</sub> = 1 A, T <sub>J</sub> = 125 °C	-	0.37	-	
		I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C	-	0.56	-	
		I⊧ = 5 A, TJ = 125 °C	-	0.59	-	
	I <sub>R</sub>	V <sub>R</sub> = 48 V, T <sub>J</sub> = 25 °C	-	1.2	-	uA
Reverse Current Per Diode		V <sub>R</sub> = 60 V, T <sub>J</sub> = 25 °C	-	1.8	50	
		V <sub>R</sub> = 60 V, T <sub>J</sub> = 125 °C	-	1.5	-	mA

NOTES :

- 1. Mounted on a FR4 PCB, single-sided copper, standard footprint.
- 2. Mounted on a FR4 PCB, single-sided copper, with 100 cm<sup>2</sup> copper pad area.





T<sub>J</sub> = 25°C

100

80

0.1 20

40

60

Percent of Rated Reverse Voltage (%)

Fig.3 Typical Forward Characteristics

0.01

0

0.2

0.4

**Fig.2 Typical Reverse Characteristics** 

0.6

V<sub>F</sub>, Forward Voltage (V)

per diode

0.8

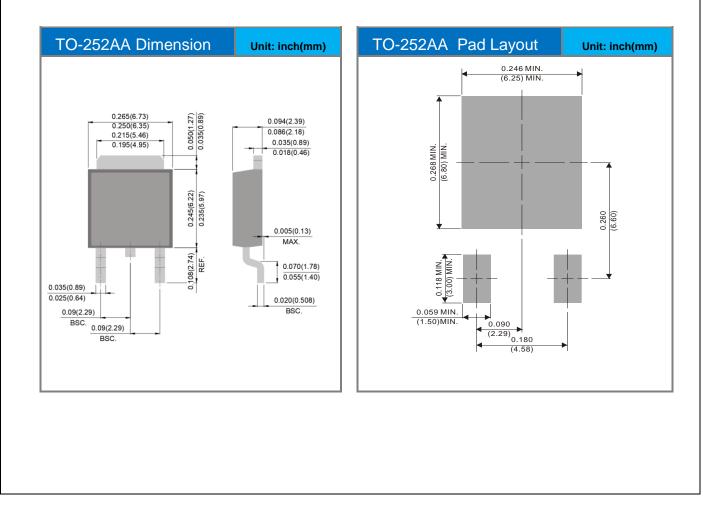
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#### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
MBR1060CD	TO-252AA	3K pcs / 13" reel	MBR1060C	

#### Packaging Information & Mounting Pad Layout





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